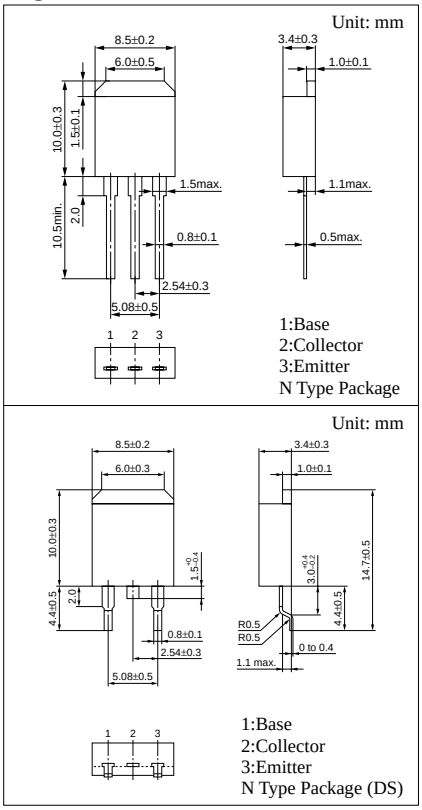
2SD1261, 2SD1261A

Silicon NPN triple diffusion planar type Darlington

For power amplification

Complementary to 2SB0938 (2SB938) and 2SB0938A (2SB938A)



Features

- High foward current transfer ratio h_{FE}
- High-speed switching
- N type package enabling direct soldering of the radiating fin to the printed circuit board, etc. of small electronic equipment.

Absolute Maximum Ratings (T_C=25˚C)

Parameter		Symbol	Ratings	Unit
Collector to base voltage	2SD1261	V_{CBO}	60	V
	2SD1261A		80	
Collector to emitter voltage	2SD1261	V_{CEO}	60	V
	2SD1261A		80	
Emitter to base voltage		V_{EBO}	5	V
Peak collector current		I_{CP}	8	A
Collector current		I_C	4	A
Collector power dissipation	T_C=25°C	P_C	40	W
	Ta=25°C		1.3	
Junction temperature		T_j	150	˚C
Storage temperature		T_{stg}	–55 to +150	˚C

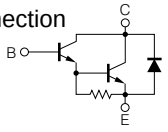
Electrical Characteristics (T_C=25˚C)

Parameter		Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	2SD1261	I_{CBO}	V_{CB} = 60V, I_E = 0			200	μA
	2SD1261A		V_{CB} = 80V, I_E = 0			200	
Collector cutoff current	2SD1261	I_{CEO}	V_{CE} = 30V, I_B = 0			500	μA
	2SD1261A		V_{CE} = 40V, I_B = 0			500	
Emitter cutoff current		I_{EBO}	V_{EB} = 5V, I_C = 0			2	mA
Collector to emitter voltage	2SD1261	V_{CEO}	I_C = 30mA, I_B = 0	60			V
	2SD1261A			80			
Forward current transfer ratio		h_{FE1}	V_{CE} = 3V, I_C = 0.5A	1000			
		h_{FE2}*	V_{CE} = 3V, I_C = 3A	1000		10000	
Base to emitter voltage		V_{BE}	V_{CE} = 3V, I_C = 3A			2.5	V
Collector to emitter saturation voltage		$V_{CE(sat)}$	I_C = 3A, I_B = 12mA			2	V
			I_C = 5A, I_B = 20mA			4	
Transition frequency		f_T	V_{CE} = 10V, I_C = 0.5A, f = 1MHz		20		MHz
Turn-on time		t_{on}	I_C = 3A, I_{B1} = 12mA, I_{B2} = –12mA, V_{CC} = 50V		0.5		μs
Storage time		t_{stg}			4		μs
Fall time		t_f			1		μs

*h_{FE2} Rank classification

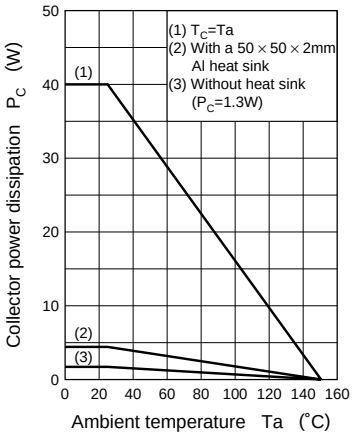
Rank	R	Q	P
h_{FE2}	1000 to 2500	2000 to 5000	4000 to 10000

Internal Connection

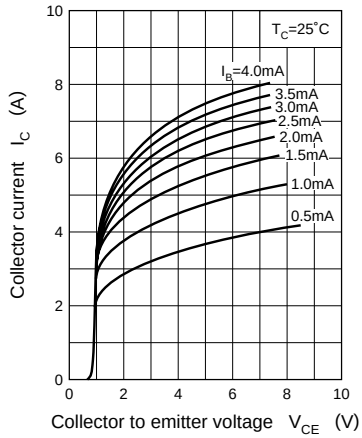


Note) The part numbers in the parenthesis show conventional part number.

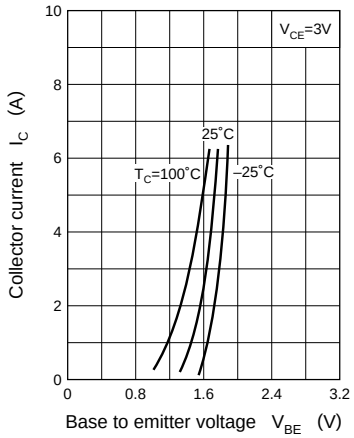
P_C — Ta



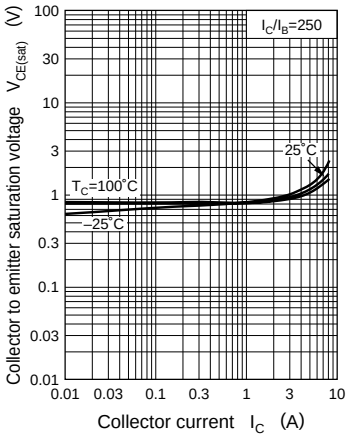
I_C — V_{CE}



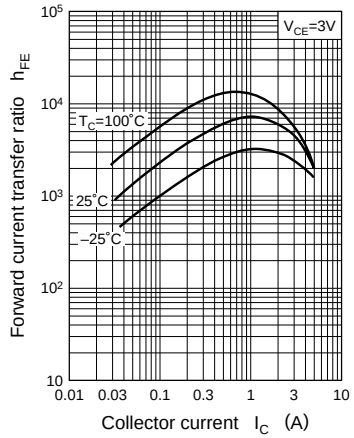
I_C — V_{BE}



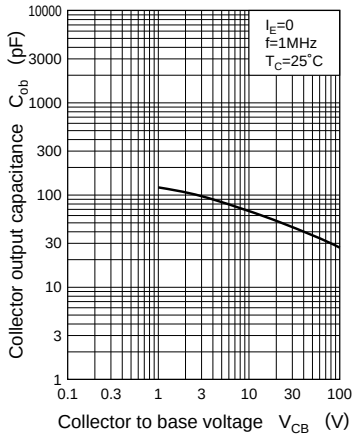
$V_{CE(sat)}$ — I_C



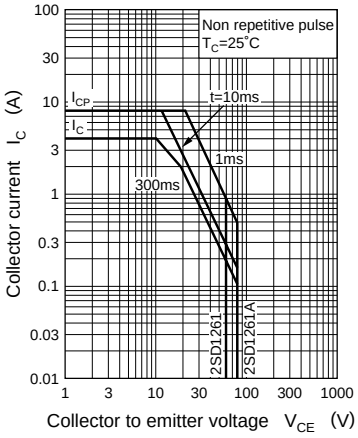
h_{FE} — I_C



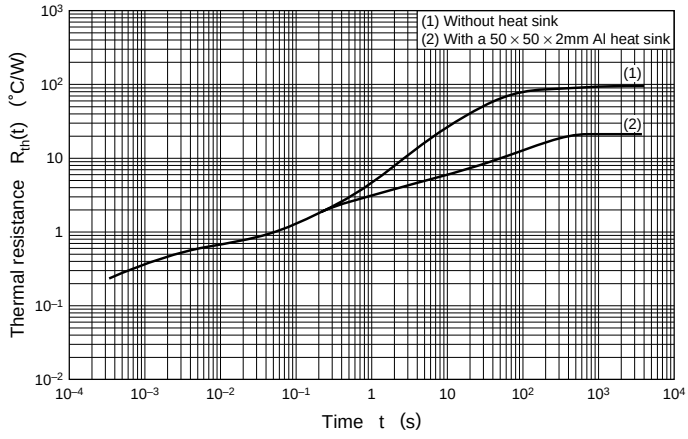
C_{ob} — V_{CB}



Area of safe operation (ASO)



$R_{th(t)}$ — t



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